

Data Sheet January 16, 2014 FN6155.5

# 39µA Micropower Rail-to-Rail Input-Output Low Input Bias Current (RRIO) Op Amp

The ISL28166 is a micropower precision operational amplifier optimized for single supply operation at 5V and can operate down to 2.4V.

This device features an Input Range Enhancement Circuit (IREC), which enables it to maintain CMRR performance for input voltages greater than the positive supply. The input signal is capable of swinging 0.5V above a 5.0V supply (0.25 for a 2.5V supply) and to within 10mV from ground. The output operation is rail-to-rail.

The 1/f corner of the voltage noise spectrum is at 1kHz. This results in low frequency noise performance, which can only be found on device with an order of magnitude higher than the supply current.

The ISL28166 can be operated from one lithium cell or two Ni-Cd batteries. The input range includes both positive and negative rail. The output swings to both rails.

## Ordering Information

PART NUMBER (Note 2)	PART MARKING	PACKAGE (Pb-Free)	PKG. DWG. #
ISL28166FHZ-T7 (Note 1)	GABY (Note 3)	6 Ld SOT-23	P6.064A
ISL28166EVAL1Z	Evaluation Board		

- 1. Please refer to TB347 for details on reel specifications.
- 2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- 3. The part marking is located on the bottom of the parts.

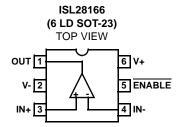
### **Features**

- 39µA typical supply current
- · 5nA max input bias current
- 250kHz gain bandwidth product (A<sub>V</sub> = 1)
- · 2.4V to 5V single supply voltage range
- Rail-to-rail input and output
- Enable pin
- Pb-free (RoHS compliant)

## **Applications**

- · Battery- or solar-powered systems
- 4mA to 20mA current loops
- · Handheld consumer products
- · Medical devices
- · Sensor amplifiers
- ADC buffers
- · DAC output amplifiers

### **Pinouts**



## **Absolute Maximum Ratings** (T<sub>A</sub> = +25°C)

Supply Voltage         5.5V           Supply Turn-on Voltage Slew Rate         1V/µs           Differential Input Current         5mA
Differential Input Voltage
Input Voltage
ESD Rating
Human Body Model
Machine Model300V
Charged Device Model

## **Thermal Information**

Thermal Resistance (Typical Note 4)	θ <sub>JA</sub> (°C/W)
6 Ld SOT-23 Package	230
Output Short-Circuit Duration	
Ambient Operating Temperature Range40	°C to +125°C
Storage Temperature Range	°C to +150°C
Operating Junction Temperature	+125°C
Pb-Free Reflow Profile	ee link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

## NOTE:

4. θ<sub>JA</sub> is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief <u>TB379</u> for details.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$ 

**Electrical Specifications**  $V_+ = 5V$ ,  $V_- = 0V$ ,  $V_{CM} = 2.5V$ ,  $T_A = +25^{\circ}C$  unless otherwise specified. **Boldface limits apply over the operating temperature range, -40°C to +125°C.** Temperature data established by characterization.

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 5)	TYP	MAX (Note 5)	UNIT
Vos	Input Offset Voltage		-700	-7	700	μV
			-800		800	
$\frac{\Delta V_{OS}}{\Delta T}$	Input Offset Drive vs Temperature			1.5		μV/°C
Ios	Input Offset Current		-1.5	0.34	1.2	nA
			-5		2.5	
I <sub>B</sub>	Input Bias Current		-5	1.14	5	nA
			-5.5		5.5	
E <sub>N</sub>	Input Noise Voltage Density	F <sub>O</sub> = 1kHz		46		nV/√Hz
I <sub>N</sub>	Input Noise Current Density	F <sub>O</sub> = 1kHz		0.14		pA/√Hz
CMIR	Input Common-Mode Voltage Range		0		5	V
CMRR	Common-Mode Rejection Ratio	V <sub>CM</sub> = 0V to 5V	80	110		dB
			75			
PSRR	Power Supply Rejection Ratio	V <sub>S</sub> = 2.4V to 5V	90	104		dB
			75			
A <sub>VOL</sub>	Large Signal Voltage Gain	$V_O = 0.5V$ to 4.5V, $R_L = 100k\Omega$	200	412		V/mV
			175			
		$V_O = 0.5V$ to 4.5V, $R_L = 1k\Omega$	35	70		V/mV
			30			
V <sub>OUT</sub>	Maximum Output Voltage Swing	Output low, $R_L = 100k\Omega$		3	6	mV
					8	
		Output low, $R_L = 1k\Omega$		130	150	mV
					200	
		Output high, $R_L = 100k\Omega$	4.992	4.995		V
			4.99			
		Output high, $R_L = 1k\Omega$	4.85	4.88		V
			4.8			
SR	Slew Rate			0.05		V/µs
GBW	Gain Bandwidth Product	A <sub>V</sub> = 1		250		kHz

intersil FN6155.5 January 16, 2014

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PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 5)	TYP	MAX (Note 5)	UNIT
I <sub>S,ON</sub>	Supply Current, Enabled			39	47	μΑ
					56	
I <sub>S,OFF</sub>	Supply Current, Disabled			10	14	μΑ
					16	
I <sub>O</sub> +	Short-Circuit Output Current	$R_L = 10\Omega$	28	31		mA
			23			
I <sub>O</sub> -	Short-Circuit Output Current	$R_L = 10\Omega$		-26	-24	mA
					-18	
V <sub>SUPPLY</sub>	Supply Operating Range	Guaranteed by PSRR test	2.4		5	V
V <sub>INH</sub>	Enable Pin High Level		2			V
$V_{INL}$	Enable Pin Low Level				0.8	V
I <sub>ENH</sub>	Enable Pin Input Current	V <sub>EN</sub> = 5V		1	1.2	μΑ
					1.2	
I <sub>ENL</sub>	Enable Pin Input Current	V <sub>EN</sub> = 0V		16	25	nA
					30	
t <sub>EN</sub>	Enable to output on-state delay time	V <sub>OUT</sub> = 1V (enable state); V <sub>EN</sub> = High-to- Low		10.8		μs
t <sub>EN</sub>	Enable to output off-state delay time	V <sub>OUT</sub> = 0V (disabled state) VEN = Low-to- High		0.1		μs

### NOTE:

# **Typical Performance Curves**

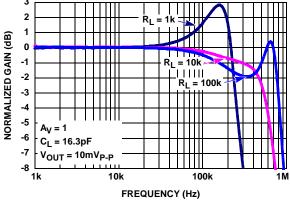


FIGURE 1. GAIN vs FREQUENCY vs RL

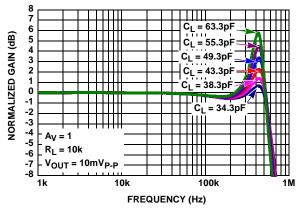


FIGURE 2. GAIN vs FREQUENCY vs CL

<sup>5.</sup> Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.

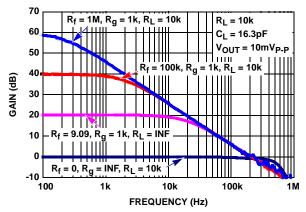


FIGURE 3. CLOSED LOOP GAIN vs FREQUENCY

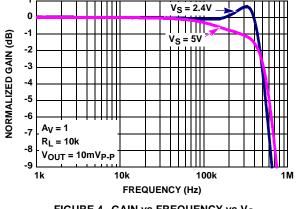


FIGURE 4. GAIN vs FREQUENCY vs VS

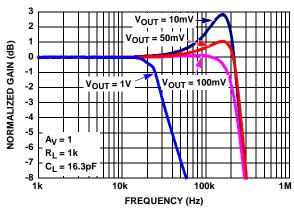


FIGURE 5. GAIN vs FREQUENCY vs VOUT

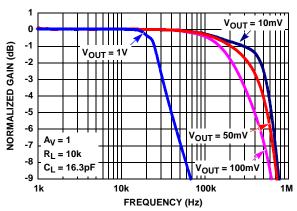


FIGURE 6. GAIN vs FREQUENCY vs V<sub>OUT</sub>

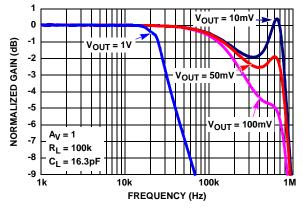


FIGURE 7. GAIN vs FREQUENCY vs V<sub>OUT</sub>

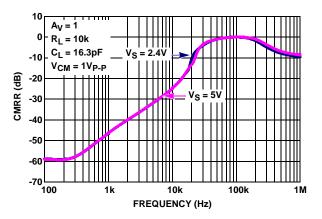


FIGURE 8. CMRR vs FREQUENCY

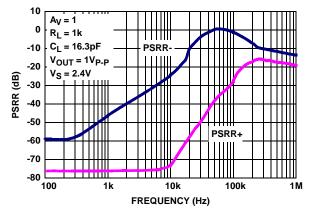


FIGURE 9. PSRR vs FREQUENCY, V<sub>S</sub> = 2.4V

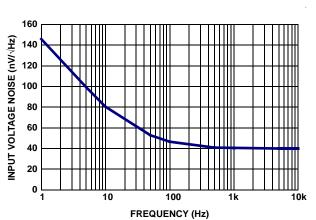


FIGURE 11. INPUT VOLTAGE NOISE vs FREQUENCY

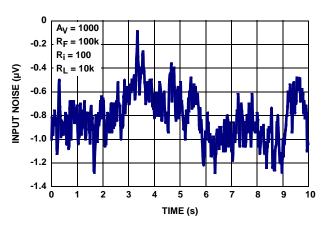


FIGURE 13. 1Hz TO 10Hz INPUT NOISE

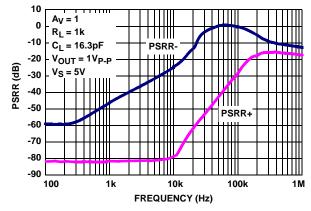


FIGURE 10. PSRR vs FREQUENCY, V<sub>S</sub> = 5V

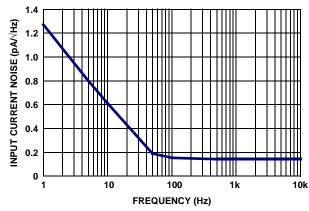


FIGURE 12. INPUT CURRENT NOISE vs FREQUENCY

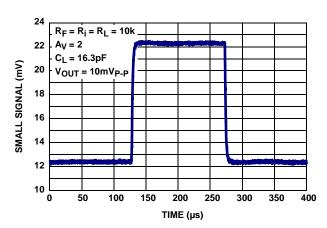


FIGURE 14. SMALL SIGNAL STEP RESPONSE

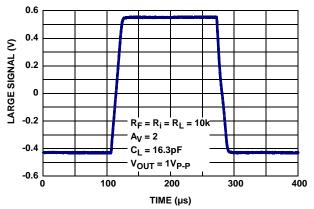


FIGURE 15. LARGE SIGNAL STEP RESPONSE

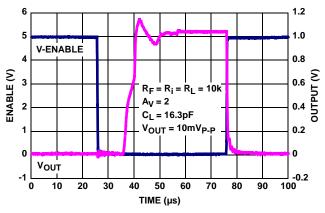


FIGURE 16. ENABLE TO OUTPUT DELAY

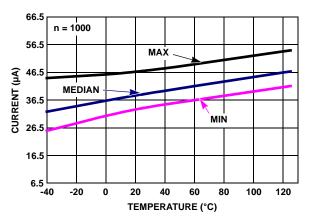


FIGURE 17. SUPPLY CURRENT ENABLED vs TEMPERATURE,  $V_S = \pm 2.5V$ 

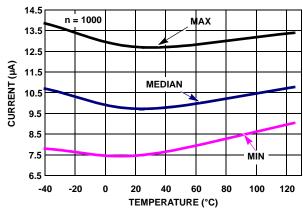


FIGURE 18. SUPPLY CURRENT DISABLED vs TEMPERATURE,  $V_S = \pm 2.5V$ 

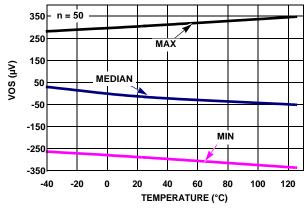


FIGURE 19. VOS vs TEMPERATURE,  $V_S = \pm 2.5V$ 

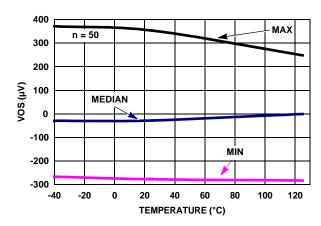


FIGURE 20. VOS vs TEMPERATURE,  $V_S = \pm 1.2V$ 

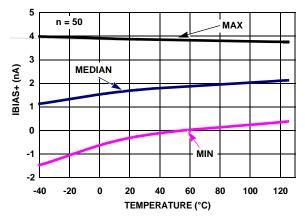


FIGURE 21. II<sub>BIAS+</sub> vs TEMPERATURE, V<sub>S</sub> = ±2.5V

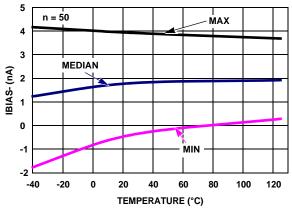


FIGURE 22.  $I_{BIAS}$  vs TEMPERATURE,  $V_S = \pm 2.5V$ 

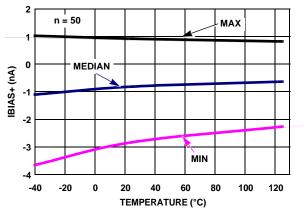


FIGURE 23.  $I_{BIAS+}$  vs TEMPERATURE,  $V_S = \pm 1.2V$ 

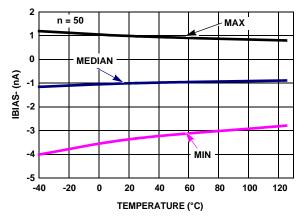


FIGURE 24.  $I_{BIAS}$  vs TEMPERATURE,  $V_S = \pm 1.2V$ 

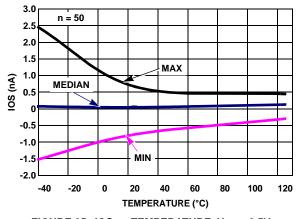


FIGURE 25. IOS vs TEMPERATURE,  $V_S = \pm 2.5V$ 

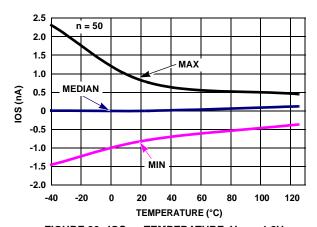


FIGURE 26. IOS vs TEMPERATURE,  $V_S = \pm 1.2V$ 

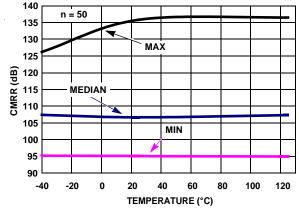


FIGURE 27. CMRR vs TEMPERATURE V+ = ±2.5V, ±1.5V

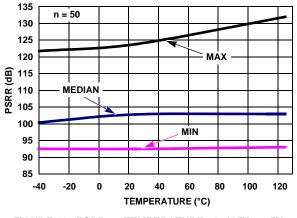


FIGURE 28. PSRR vs TEMPERATURE ±1.2V TO ±2.5V

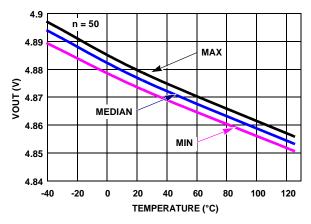


FIGURE 29.  $V_{OUT}$  HIGH vs TEMP  $V_{S} = \pm 2.5V$ ,  $R_{L} = 1k$ 

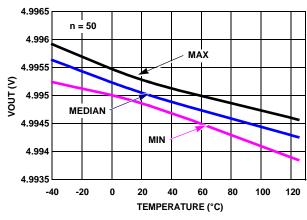


FIGURE 30.  $V_{OUT}$  HIGH  $V_{S} = \pm 2.5V$ ,  $R_{L} = 100k$ 

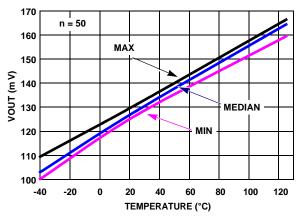


FIGURE 31.  $V_{OUT}$  LOW  $V_{S} = \pm 2.5V$ ,  $R_{L} = 1k$ 

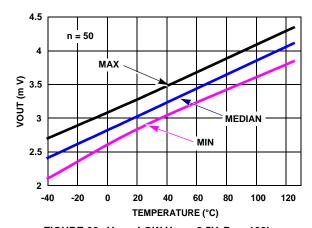


FIGURE 32.  $V_{OUT}$  LOW  $V_{S}$  = ±2.5V,  $R_{L}$  = 100k

# Pin Descriptions

ISL28166 (6 Ld SOT-23)	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
4	IN-	Inverting input	IN- IN- IN+ V-
3	IN+	Non-inverting input	(See Circuit 1)
2	V-	Negative supply	
1	OUT	Output	V+ OUT Circuit 2
6	V+	Positive supply	
5	ENABLE	Chip enable	CE UV-

## Applications Information

### Introduction

The ISL28166 is a BiMOS rail-to-rail input, output (RRIO) operational amplifier with an enable feature. The device is designed to operate from single supply (2.4V to 5.0V) or dual supplies ( $\pm 1.2V$  to  $\pm 2.5V$ ) while drawing only 39 $\mu$ A of supply current. This combination of low power and precision performance makes this device suitable for a variety of low power applications including battery powered systems.

## Rail-to-Rail Input/Output

This device feature bi-polar input which has an input common mode range that extends to the rails and CMOS outputs that can typically swing to within about 4mV of the supply rails with a  $100 k\Omega$  load. The NMOS sinks current to swing the output in the negative direction. The PMOS sources current to swing the output in the positive direction.

## Input Protection

All input terminals have internal ESD protection diodes to both positive and negative supply rails, limiting the input voltage to within one diode beyond the supply rails. They also contain back-to-back diodes across the input terminals. For applications where the input differential voltage is expected to exceed 0.5V, external series resistors must be used to ensure the input currents never exceed 5mA (Figure 33).

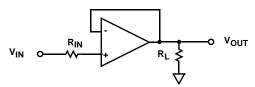


FIGURE 33. INPUT CURRENT LIMITING

### Enable/Disable Feature

The ISL28166 offers an  $\overline{\text{EN}}$  pin that disables the device when pulled up to at least 2.0V. In the disabled state (output in a high impedance state), the part consumes typically 10µA. By disabling the part, multiple ISL28166 parts can be connected together as a MUX. In this configuration, the outputs are tied together in parallel and a channel can be selected by the  $\overline{\text{EN}}$  pin. The  $\overline{\text{EN}}$  pin also has an internal pull-down. If left open, the  $\overline{\text{EN}}$  pin will pull to the negative rail and the device will be enabled by default.

The loading effects of the feedback resistors of the disabled amplifier must be considered when multiple amplifier outputs are connected together.

## **Current Limiting**

This device has no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

## **Power Dissipation**

It is possible to exceed the +125°C maximum junction temperatures under certain load and power-supply conditions. It is therefore important to calculate the maximum junction temperature (T<sub>JMAX</sub>) for all applications to determine if power supply voltages, load conditions, or package type need to be modified to remain in the safe operating area. These parameters are related in Equation 1:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} x PD_{MAXTOTAL})$$
 (EQ. 1)

#### where:

- P<sub>DMAXTOTAL</sub> is the sum of the maximum power dissipation of each amplifier in the package (PD<sub>MAX</sub>)
- PD<sub>MAX</sub> for each amplifier can be calculated using Equation 2:

$$PD_{MAX} = 2*V_{S} \times I_{SMAX} + (V_{S} - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_{L}}$$
(EQ. 2)

### where:

- T<sub>MAX</sub> = Maximum ambient temperature
- $\theta_{JA}$  = Thermal resistance of the package
- PD<sub>MAX</sub> = Maximum power dissipation of 1 amplifier
- V<sub>S</sub> = Supply voltage
- I<sub>MAX</sub> = Maximum supply current of 1 amplifier
- V<sub>OUTMAX</sub> = Maximum output voltage swing of the application
- R<sub>I</sub> = Load resistance

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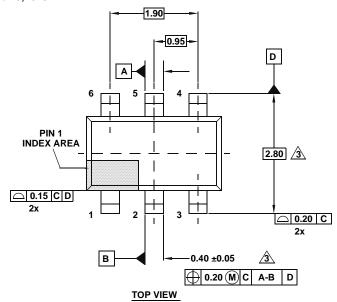
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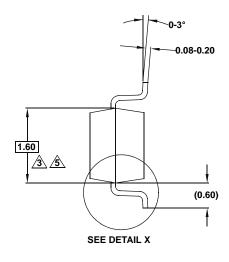
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# **Package Outline Drawing**

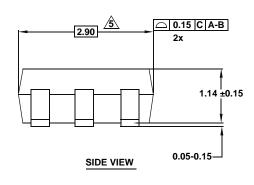
# P6.064A

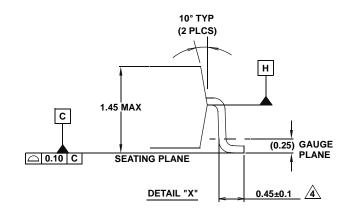
6 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE Rev 0, 2/10

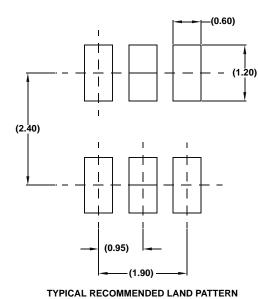




**END VIEW** 







### NOTES:

- Dimensions are in millimeters.
   Dimensions in ( ) for Reference Only.
- 2. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
- 3. Dimension is exclusive of mold flash, protrusions or gate burrs.
- 4. Foot length is measured at reference to guage plane.
- 5. This dimension is measured at Datum "H".
- 6. Package conforms to JEDEC MO-178AA.